

To all our customers

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Renesas Technology Corp.  
Customer Support Dept.  
April 1, 2003

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Keep safety first in your circuit designs!

1. Renesas Technology Corporation puts the maximum effort into making semiconductor products better and more reliable, but there is always the possibility that trouble may occur with them. Trouble with semiconductors may lead to personal injury, fire or property damage.

Remember to give due consideration to safety when making your circuit designs, with appropriate measures such as (i) placement of substitutive, auxiliary circuits, (ii) use of nonflammable material or (iii) prevention against any malfunction or mishap.

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# 2SC4965

Silicon NPN Epitaxial

**RENESAS**

ADE-208-006A (Z)  
2nd. Edition  
Mar. 2001

## Application

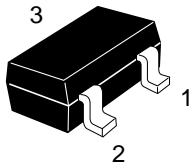
VHF / UHF RF switch

## Features

- Low  $R_{on}$  and high performance for RF switch.
- Capable of high density mounting.

## Outline

CMPAK



1. Emitter
2. Base
3. Collector

Note: Marking is "YV-".

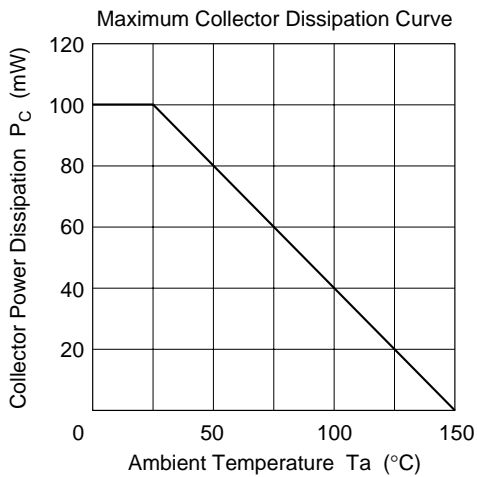
Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings	Unit
Collector to base voltage	$V_{CBO}$	12	V
Collector to emitter voltage	$V_{CEO}$	8	V
Emitter to base voltage	$V_{EBO}$	3	V
Collector current	$I_C$	100	mA
Collector power dissipation	$P_C$	100	mW
Junction temperature	$T_j$	150	°C
Storage temperature	$T_{stg}$	-55 to +150	°C

Electrical Characteristics (Ta = 25°C)

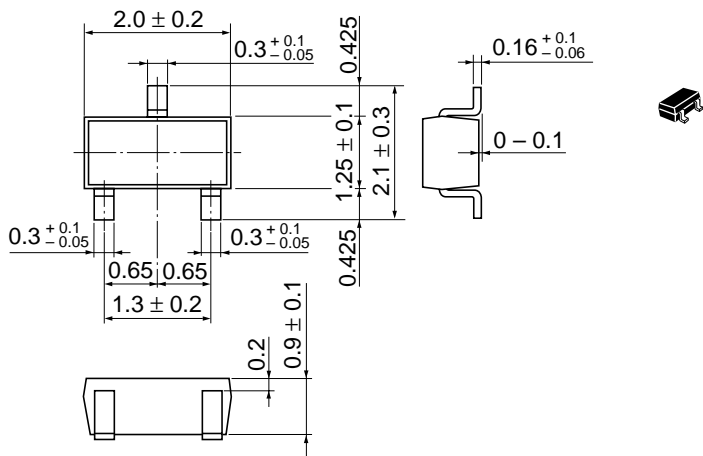
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	12	—	—	V	$I_C = 10\text{ }\mu\text{A}$ , $I_E = 0$
Collector cutoff current	$I_{CBO}$	—	—	10	$\mu\text{A}$	$V_{CB} = 10\text{ V}$ , $I_E = 0$
	$I_{CEO}$	—	—	1	mA	$V_{CE} = 8\text{ V}$ , $R_{BE} =$
Emitter cutoff current	$I_{EBO}$	—	—	10	$\mu\text{A}$	$V_{EB} = 3\text{ V}$ , $I_C = 0$
DC current transfer ratio	$h_{FE}$	100	250	600		$V_{CE} = 5\text{ V}$ , $I_C = 5\text{ mA}$
Collector to emitter saturation voltage	$V_{CE(sat)}$	—	150	300	mV	$I_C = 80\text{ mA}$ , $I_B = 5\text{ mA}$
Collector output capacitance	$C_{ob}$	—	1.9	1.6	pF	$V_{CB} = 5\text{ V}$ , $I_E = 0$ , $f = 1\text{ MHz}$
On resistance	$R_{on}$	—	1.2	—		$I_B = 2.5\text{ mA}$ , $f = 1\text{ kHz}$

See characteristic curves of 2SC4964.



Package Dimensions

As of January, 2001  
Unit: mm



Hitachi Code	CMPAK
JEDEC	—
EIAJ	Conforms
Mass (reference value)	0.006 g

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